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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	e200z0h
Core Size	32-Bit Single-Core
Speed	64MHz
Connectivity	CANbus, LINbus, SPI, UART/USART
Peripherals	DMA, POR, PWM, WDT
Number of I/O	37
Program Memory Size	256KB (256K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	20K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 3.6V
Data Converters	A/D 16x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/spc560p40l1cefby

1.5 Feature details

1.5.1 High performance e200z0 core processor

The e200z0 Power Architecture core provides the following features:

- High performance e200z0 core processor for managing peripherals and interrupts
- Single issue 4-stage pipeline in-order execution 32-bit Power Architecture CPU
- Harvard architecture
- Variable length encoding (VLE), allowing mixed 16- and 32-bit instructions
  - Results in smaller code size footprint
  - Minimizes impact on performance
- Branch processing acceleration using lookahead instruction buffer
- Load/store unit
  - 1-cycle load latency
  - Misaligned access support
  - No load-to-use pipeline bubbles
- Thirty-two 32-bit general purpose registers (GPRs)
- Separate instruction bus and load/store bus Harvard architecture
- Hardware vectored interrupt support
- Reservation instructions for implementing read-modify-write constructs
- Long cycle time instructions, except for guarded loads, do not increase interrupt latency
- Extensive system development support through Nexus debug port
- Non-maskable interrupt support

1.5.2 Crossbar switch (XBAR)

The XBAR multi-port crossbar switch supports simultaneous connections between three master ports and three slave ports. The crossbar supports a 32-bit address bus width and a 32-bit data bus width.

The crossbar allows for two concurrent transactions to occur from any master port to any slave port; but one of those transfers must be an instruction fetch from internal flash memory. If a slave port is simultaneously requested by more than one master port, arbitration logic will select the higher priority master and grant it ownership of the slave port. All other masters requesting that slave port will be stalled until the higher priority master completes its transactions. Requesting masters will be treated with equal priority and will be granted access a slave port in round-robin fashion, based upon the ID of the last master to be granted access.

1.5.6 Interrupt controller (INTC)

The interrupt controller (INTC) provides priority-based preemptive scheduling of interrupt requests, suitable for statically scheduled hard real-time systems. The INTC handles 128 selectable-priority interrupt sources.

For high-priority interrupt requests, the time from the assertion of the interrupt request by the peripheral to the execution of the interrupt service routine (ISR) by the processor has been minimized. The INTC provides a unique vector for each interrupt request source for quick determination of which ISR has to be executed. It also provides a wide number of priorities so that lower priority ISRs do not delay the execution of higher priority ISRs. To allow the appropriate priorities for each source of interrupt request, the priority of each interrupt request is software configurable.

When multiple tasks share a resource, coherent accesses to that resource need to be supported. The INTC supports the priority ceiling protocol (PCP) for coherent accesses. By providing a modifiable priority mask, the priority can be raised temporarily so that all tasks which share the same resource can not preempt each other.

The INTC provides the following features:

- Unique 9-bit vector for each separate interrupt source
- 8 software triggerable interrupt sources
- 16 priority levels with fixed hardware arbitration within priority levels for each interrupt source
- Ability to modify the ISR or task priority: modifying the priority can be used to implement the priority ceiling protocol for accessing shared resources.
- 1 external high priority interrupt (NMI) directly accessing the main core and I/O processor (IOP) critical interrupt mechanism

1.5.7 System status and configuration module (SSCM)

The system status and configuration module (SSCM) provides central device functionality.

The SSCM includes these features:

- System configuration and status
  - Memory sizes/status
  - Device mode and security status
  - Determine boot vector
  - Search code flash for bootable sector
  - DMA status
- Debug status port enable and selection
- Bus and peripheral abort enable/disable

1.5.8 System clocks and clock generation

The following list summarizes the system clock and clock generation on the SPC560P34/SPC560P40:

- Lock detect circuitry continuously monitors lock status
- Loss of clock (LOC) detection for PLL outputs
- Programmable output clock divider (÷1, ÷2, ÷4, ÷8)
- FlexPWM module and eTimer module running at the same frequency as the e200z0h core
- Internal 16 MHz RC oscillator for rapid start-up and safe mode: supports frequency trimming by user application

1.5.9 Frequency-modulated phase-locked loop (FMPLL)

The FMPLL allows the user to generate high speed system clocks from a 4–40 MHz input clock. Further, the FMPLL supports programmable frequency modulation of the system clock. The PLL multiplication factor, output clock divider ratio are all software configurable.

The FMPLL has the following major features:

- Input clock frequency: 4–40 MHz
- Maximum output frequency: 64 MHz
- Voltage controlled oscillator (VCO)—frequency 256–512 MHz
- Reduced frequency divider (RFD) for reduced frequency operation without forcing the FMPLL to relock
- Frequency-modulated PLL
  - Modulation enabled/disabled through software
  - Triangle wave modulation
- Programmable modulation depth (±0.25% to ±4% deviation from center frequency): programmable modulation frequency dependent on reference frequency
- Self-clocked mode (SCM) operation

1.5.10 Main oscillator

The main oscillator provides these features:

- Input frequency range: 4–40 MHz
- Crystal input mode or oscillator input mode
- PLL reference

1.5.11 Internal RC oscillator

This device has an RC ladder phase-shift oscillator. The architecture uses constant current charging of a capacitor. The voltage at the capacitor is compared by the stable bandgap reference voltage.

1.5.16 System integration unit – Lite (SIUL)

The SPC560P34/SPC560P40 SIUL controls MCU pad configuration, external interrupt, general purpose I/O (GPIO), and internal peripheral multiplexing.

The pad configuration block controls the static electrical characteristics of I/O pins. The GPIO block provides uniform and discrete input/output control of the I/O pins of the MCU.

The SIUL provides the following features:

- Centralized general purpose input output (GPIO) control of up to 49 input/output pins and 16 analog input-only pads (package dependent)
- All GPIO pins can be independently configured to support pull-up, pull-down, or no pull
- Reading and writing to GPIO supported both as individual pins and 16-bit wide ports
- All peripheral pins, except ADC channels, can be alternatively configured as both general purpose input or output pins
- ADC channels support alternative configuration as general purpose inputs
- Direct readback of the pin value is supported on all pins through the SIUL
- Configurable digital input filter that can be applied to some general purpose input pins for noise elimination
- Up to 4 internal functions can be multiplexed onto 1 pin

1.5.17 Boot and censorship

Different booting modes are available in the SPC560P34/SPC560P40: booting from internal flash memory and booting via a serial link.

The default booting scheme uses the internal flash memory (an internal pull-down resistor is used to select this mode). Optionally, the user can boot via FlexCAN or LINFlex (using the boot assist module software).

A censorship scheme is provided to protect the content of the flash memory and offer increased security for the entire device.

A password mechanism is designed to grant the legitimate user access to the non-volatile memory.

Boot assist module (BAM)

The BAM is a block of read-only memory that is programmed once and is identical for all SPC560Pxx devices that are based on the e200z0h core. The BAM program is executed every time the device is powered on if the alternate boot mode has been selected by the user.

The BAM provides the following features:

- Serial bootloading via FlexCAN or LINFlex
- Ability to accept a password via the used serial communication channel to grant the legitimate user access to the non-volatile memory

1.5.18 Error correction status module (ECSM)

The ECSM provides a myriad of miscellaneous control functions regarding program-visible information about the platform configuration and revision levels, a reset status register, a software watchdog timer, wakeup control for exiting sleep modes, and information on

1.5.31 On-chip voltage regulator (VREG)

The on-chip voltage regulator module provides the following features:

- Uses external NPN (negative-positive-negative) transistor
- Regulates external 3.3 V/5.0 V down to 1.2 V for the core logic
- Low voltage detection on the internal 1.2 V and I/O voltage 3.3 V

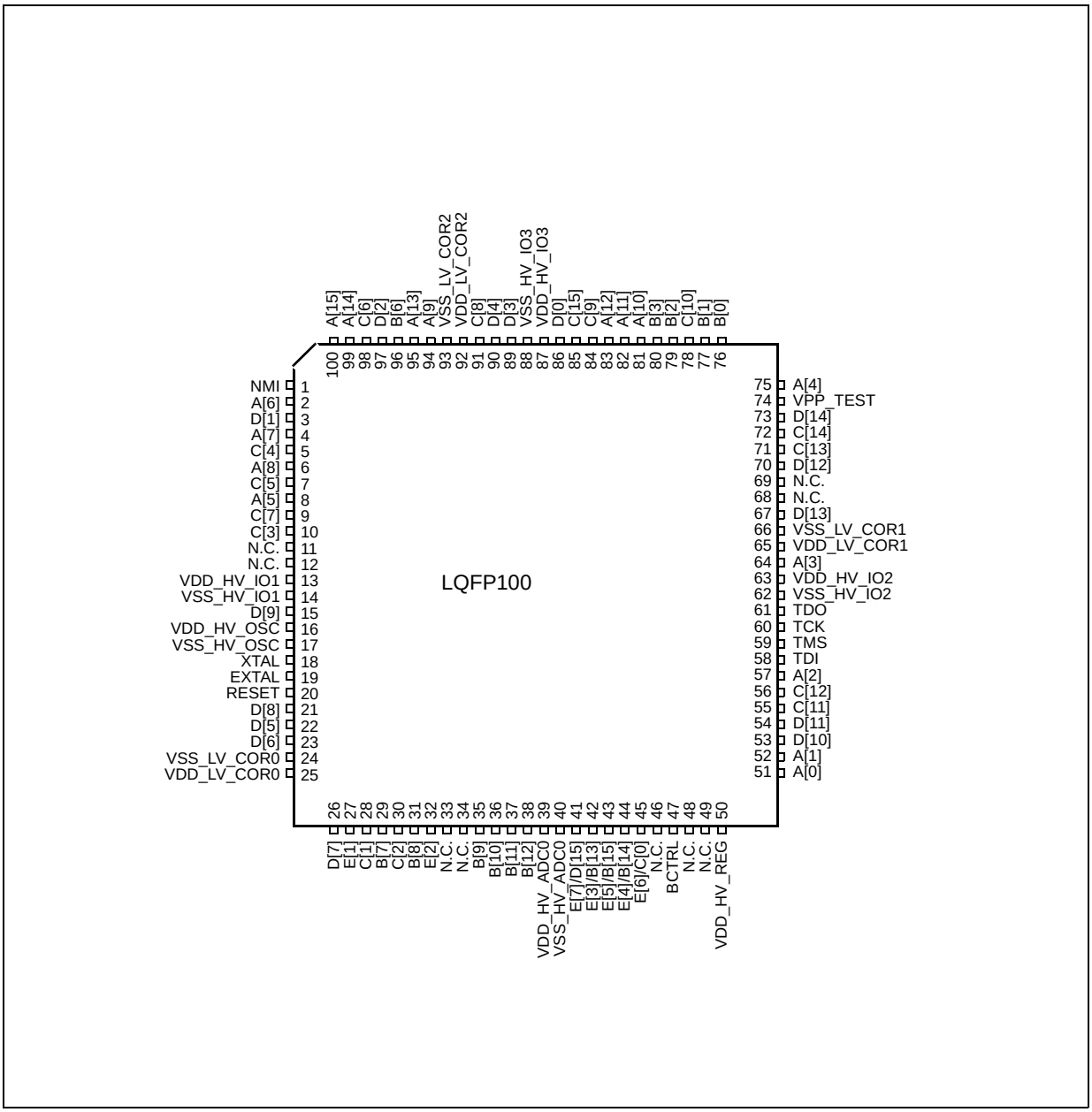


Figure 5. 100-pin LQFP pinout – Airbag configuration (top view)

Table 5. Supply pins (continued)

Supply		Pin	
Symbol	**Description**	**64-pin**	**100-pin**
$V_{DD\_LV\_COR2}$	1.2 V supply pins for core logic and code Flash. Decoupling capacitor must be connected between these pins and the nearest $V_{SS\_LV\_COR}$ pin.	58	92
$V_{SS\_LV\_COR2}$	1.2 V supply pins for core logic and code Flash. Decoupling capacitor must be connected betwee.n these pins and the nearest $V_{DD\_LV\_COR}$ pin.	59	93

1. Analog supply/ground and high/low reference lines are internally physically separate, but are shorted via a double-bonding connection on $V_{DD\_HV\_ADCx}$/$V_{SS\_HV\_ADCx}$ pins.

2.2.2 System pins

Table 6 and *Table 7* contain information on pin functions for the SPC560P34/SPC560P40 devices. The pins listed in *Table 6* are single-function pins. The pins shown in *Table 7* are multi-function pins, programmable via their respective pad configuration register (PCR) values.

Table 6. System pins

Symbol	Description	Direction	Pad speed(1)		Pin	
			SRC = 0	SRC = 1	64-pin	100-pin
Dedicated pins						
NMI	Non-maskable Interrupt	Input only	Slow	—	1	1
XTAL	Analog output of the oscillator amplifier circuit—needs to be grounded if oscillator is used in bypass mode	—	—	—	11	18
EXTAL	Analog input of the oscillator amplifier circuit, when the oscillator is not in bypass mode Analog input for the clock generator when the oscillator is in bypass mode	—	—	—	12	19
TDI	JTAG test data input	Input only	Slow	—	35	58
TMS	JTAG state machine control	Input only	Slow	—	36	59
TCK	JTAG clock	Input only	Slow	—	37	60
TDO	JTAG test data output	Output only	Slow	Fast	38	61
Reset pin						
$\overline{\text{RESET}}$	Bidirectional reset with Schmitt trigger characteristics and noise filter	Bidirectional	Medium	—	13	20
Test pin						
VPP_TEST	Pin for testing purpose only. To be tied to ground in normal operating mode.	—	—	—	47	74

1. SRC values refer to the value assigned to the Slew Rate Control bits of the pad configuration register.

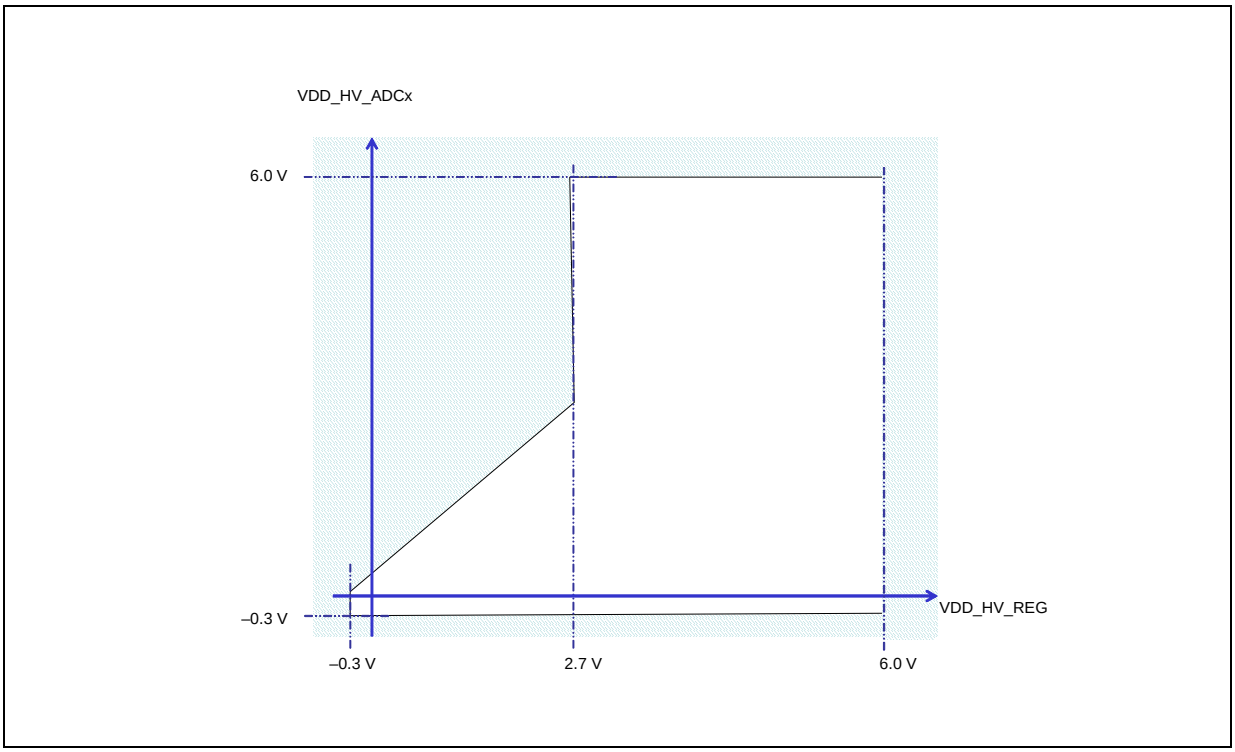


Figure 7. Independent ADC supply (–0.3 V ≤ $V_{DD\_HV\_REG}$ ≤ 6.0 V)

3.4 Recommended operating conditions

Table 10. Recommended operating conditions (5.0 V)

Symbol		Parameter	Conditions	Value		Unit
				Min	Max(1)	
V_{SS}	SR	Device ground	—	0	0	V
$V_{DD\_HV\_IOx}$(2)	SR	5.0 V input/output supply voltage	—	4.5	5.5	V
$V_{SS\_HV\_IOx}$	SR	Input/output ground voltage	—	0	0	V
$V_{DD\_HV\_OSC}$	SR	5.0 V crystal oscillator amplifier supply voltage	—	4.5	5.5	V
			Relative to $V_{DD\_HV\_IOx}$	$V_{DD\_HV\_IOx}$ – 0.1	$V_{DD\_HV\_IOx}$ + 0.1	
$V_{SS\_HV\_OSC}$	SR	5.0 V crystal oscillator amplifier reference voltage	—	0	0	V
$V_{DD\_HV\_REG}$	SR	5.0 V voltage regulator supply voltage	—	4.5	5.5	V
			Relative to $V_{DD\_HV\_IOx}$	$V_{DD\_HV\_IOx}$ – 0.1	$V_{DD\_HV\_IOx}$ + 0.1	

Table 15. Approved NPN ballast components

Part	Manufacturer	Approved derivatives(1)
BC817	Infineon	BC817-16; BC817-25; BC817SU
	NXP	BC817-16; BC817-25
BCP56	ST	BCP56-16
	Infineon	BCP56-10; BCP56-16
	ON Semi	BCP56-10
	NXP	BCP56-10; BCP56-16

1. For automotive applications please check with the appropriate transistor vendor for automotive grade certification

Table 16. Voltage regulator electrical characteristics

Symbol		C	Parameter	Conditions	Value			Unit
					Min	Typ	Max	
$V_{DD\_LV\_REGCOR}$	CC	P	Output voltage under maximum load run supply current configuration	Post-trimming	1.15	—	1.32	V
C_{DEC1}	SR	—	External decoupling/stability ceramic capacitor	BJT from *Table 15*. Three capacitors (i.e. X7R or X8R capacitors) with nominal value of 10 µF	19.5	30	—	µF
				BJT BC817, one capacitance of 22 µF	14.3	22	—	µF
R_{REG}	SR	—	Resulting ESR of either one or all three C_{DEC1}	Absolute maximum value between 100 kHz and 10 MHz	—	—	45	mΩ
C_{DEC2}	SR	—	External decoupling/stability ceramic capacitor	Four capacitances (i.e. X7R or X8R capacitors) with nominal value of 440 nF	1200	1760	—	nF
C_{DEC3}	SR	—	External decoupling/stability ceramic capacitor on VDD_HV_REG	Three capacitors (i.e. X7R or X8R capacitors) with nominal value of 10 µF; C_{DEC3} has to be equal or greater than C_{DEC1}	19.5	30	—	µF
L_{Reg}	SR	—	Resulting ESL of $V_{DD\_HV\_REG}$, BCTRL and $V_{DD\_LV\_CORx}$ pins	—	—	—	5	nH

3.8.2 Voltage monitor electrical characteristics

The device implements a power on reset module to ensure correct power-up initialization, as well as three low voltage detectors to monitor the V_{DD} and the V_{DD_LV} voltage while device is supplied:

- POR monitors V_{DD} during the power-up phase to ensure device is maintained in a safe reset state
- LVDHV3 monitors V_{DD} to ensure device reset below minimum functional supply
- LVDHV5 monitors V_{DD} when application uses device in the 5.0 V ± 10% range
- LVDLVCOR monitors low voltage digital power domain

Table 17. Low voltage monitor electrical characteristics

Symbol	C	Parameter	Conditions[1]	Value		Unit
				Min	Max	
V_{PORH}	T	Power-on reset threshold	—	1.5	2.7	V
V_{PORUP}	P	Supply for functional POR module	T_A = 25 °C	1.0	—	V
$V_{REGLVDMOK\_H}$	P	Regulator low voltage detector high threshold	—	—	2.95	V
$V_{REGLVDMOK\_L}$	P	Regulator low voltage detector low threshold	—	2.6	—	V
$V_{FLLVDMOK\_H}$	P	Flash low voltage detector high threshold	—	—	2.95	V
$V_{FLLVDMOK\_L}$	P	Flash low voltage detector low threshold	—	2.6	—	V
$V_{IOLVDMOK\_H}$	P	I/O low voltage detector high threshold	—	—	2.95	V
$V_{IOLVDMOK\_L}$	P	I/O low voltage detector low threshold	—	2.6	—	V
$V_{IOLVDM5OK\_H}$	P	I/O 5 V low voltage detector high threshold	—	—	4.4	V
$V_{IOLVDM5OK\_L}$	P	I/O 5 V low voltage detector low threshold	—	3.8	—	V
$V_{MLVDDOK\_H}$	P	Digital supply low voltage detector high	—	—	1.145	V
$V_{MLVDDOK\_L}$	P	Digital supply low voltage detector low	—	1.08	—	V

1. V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = –40 °C to $T_{A\ MAX}$, unless otherwise specified

3.9 Power up/down sequencing

To prevent an overstress event or a malfunction within and outside the device, the SPC560P34/SPC560P40 implements the following sequence to ensure each module is started only when all conditions for switching it ON are available:

- A POWER_ON module working on voltage regulator supply controls the correct start-up of the regulator. This is a key module ensuring safe configuration for all voltage regulator functionality when supply is below 1.5 V. Associated POWER_ON (or POR) signal is active low.
- Several low voltage detectors, working on voltage regulator supply monitor the voltage of the critical modules (voltage regulator, I/Os, flash memory and low voltage domain). LVDs are gated low when POWER_ON is active.
- A POWER_OK signal is generated when all critical supplies monitored by the LVD are available. This signal is active high and released to all modules including I/Os, flash

memory and 16 MHz RC oscillator needed during power-up phase and reset phase. When POWER_OK is low the associated modules are set into a safe state.

Figure 11. Power-up typical sequence

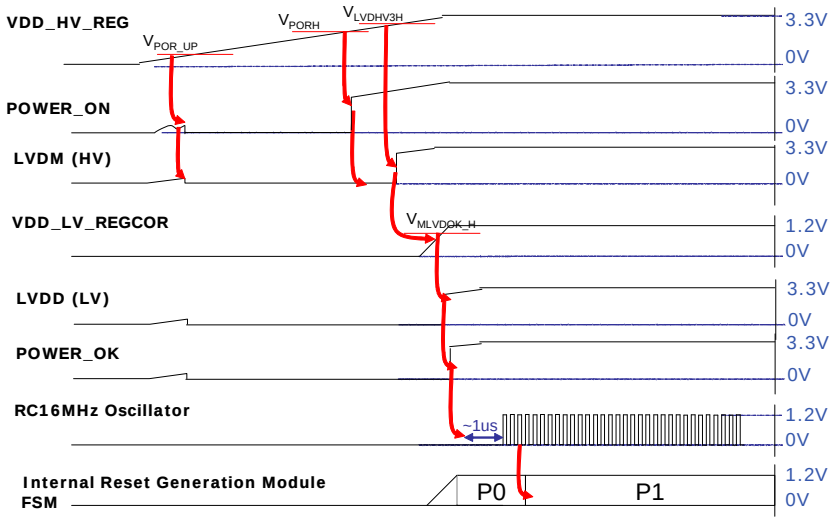
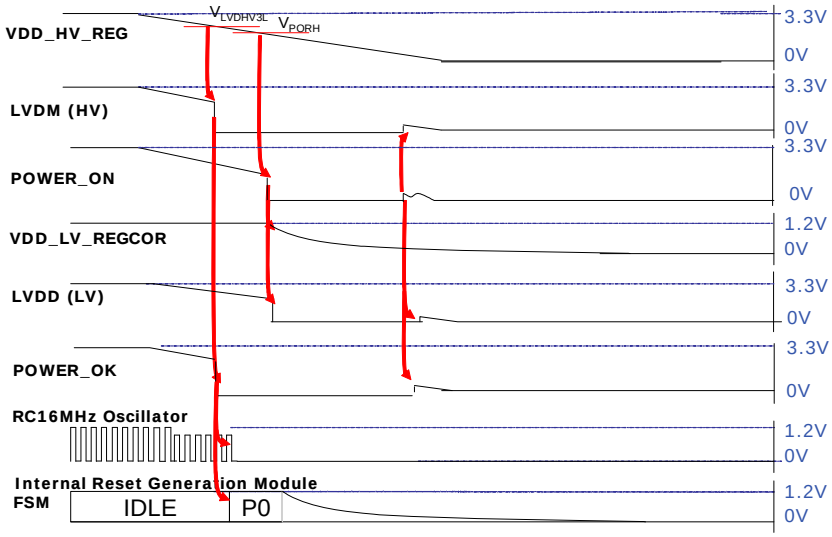
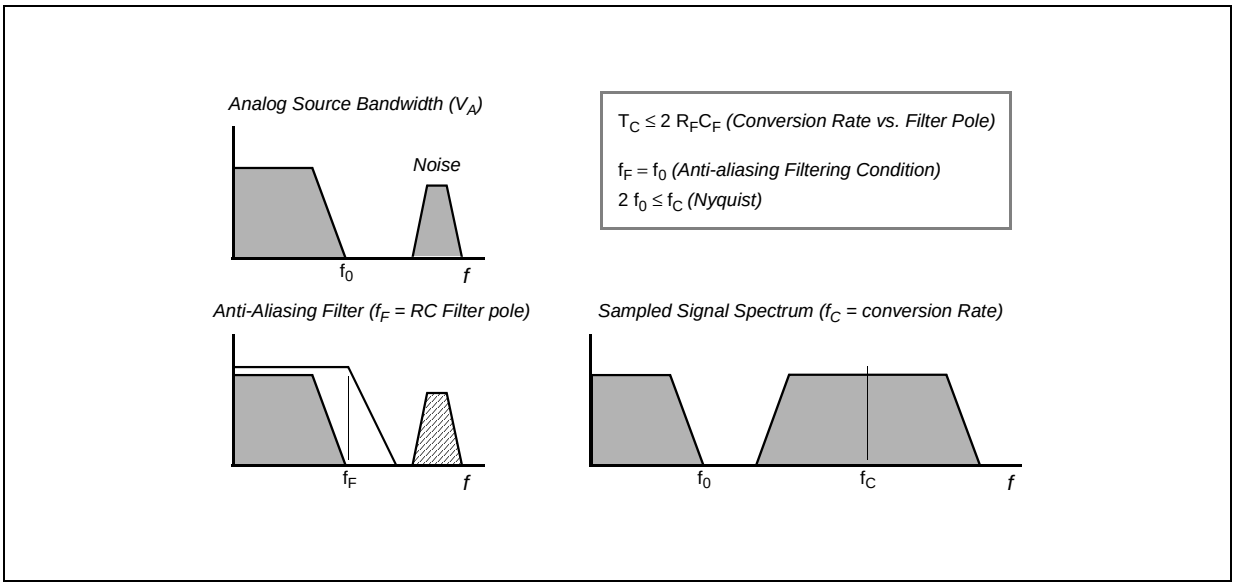


Figure 12. Power-down typical sequence



The two transients above are not influenced by the voltage source that, due to the presence of the R_FC_F filter, is not able to provide the extra charge to compensate the voltage drop on C_S with respect to the ideal source V_A; the time constant R_FC_F of the filter is very high with respect to the sampling time (T_S). The filter is typically designed to act as anti-aliasing.

Figure 18. Spectral representation of input signal



Calling f_0 the bandwidth of the source signal (and as a consequence the cut-off frequency of the anti-aliasing filter, f_F), according to the Nyquist theorem the conversion rate f_C must be at least $2f_0$; it means that the constant time of the filter is greater than or at least equal to twice the conversion period (T_C). Again the conversion period T_C is longer than the sampling time T_S, which is just a portion of it, even when fixed channel continuous conversion mode is selected (fastest conversion rate at a specific channel): in conclusion it is evident that the time constant of the filter R_FC_F is definitively much higher than the sampling time T_S, so the charge level on C_S cannot be modified by the analog signal source during the time in which the sampling switch is closed.

The considerations above lead to impose new constraints on the external circuit, to reduce the accuracy error due to the voltage drop on C_S; from the two charge balance equations above, it is simple to derive *Equation 11* between the ideal and real sampled voltage on C_S:

Equation 11

$$\frac{V_A}{V_{A2}} = \frac{C_{P1} + C_{P2} + C_F}{C_{P1} + C_{P2} + C_F + C_S}$$

From this formula, in the worst case (when V_A is maximum, that is for instance 5 V), assuming to accept a maximum error of half a count, a constraint is evident on C_F value:

Equation 12

$$C_F > 2048 \bullet C_S$$

4. During the sampling time the input capacitance C_S can be charged/discharged by the external source. The internal resistance of the analog source must allow the capacitance to reach its final voltage level within t_s. After the end of the sampling time t_s, changes of the analog input voltage have no effect on the conversion result. Values for the sample clock t_s depend on programming.
5. This parameter includes the sampling time t_s.
6. 20 MHz ADC clock. Specific prescaler is programmed on MC_PLL_CLK to provide 20 MHz clock to the ADC.
7. See *Figure 16*.

3.15 Flash memory electrical characteristics

3.15.1 Program/Erase characteristics

Table 31. Program and erase specifications

Symbol	C	Parameter	Value				Unit
			Min	Typ(1)	Initial Max(2)	Max(3)	
$T_{wprogram}$	P	Word Program Time for data flash memory(4)	—	30	70	500	µs
$T_{dwprogram}$	P	Double Word Program Time for code flash memory(4)	—	22	50	500	µs
T_{BKPRG}	P	Bank Program (256 KB)(4)(5)	—	0.73	0.83	17.5	s
	P	Bank Program (64 KB)(4)(5)	—	0.49	1.2	4.1	s
$T_{16kpperase}$	P	16 KB Block Pre-program and Erase Time for code flash memory	—	300	500	5000	ms
		16 KB Block Pre-program and Erase Time for data flash memory	—	700	800	5000	
$T_{32kpperase}$	P	32 KB Block Pre-program and Erase Time	—	400	600	5000	ms
$T_{128kpperase}$	P	128 KB Block Pre-program and Erase Time	—	800	1300	7500	ms
t_{ESRT}	P	Program and erase specifications(6)	10	—	—	—	ms

1. Typical program and erase times assume nominal supply values and operation at 25 °C. All times are subject to change pending device characterization.
2. Initial factory condition: < 100 program/erase cycles, 25 °C, typical supply voltage.
3. The maximum program and erase times occur after the specified number of program/erase cycles. These maximum values are characterized but not guaranteed.
4. Actual hardware programming times. This does not include software overhead.
5. Typical Bank programming time assumes that all cells are programmed in a single pulse. In reality some cells will require more than one pulse, adding a small overhead to total bank programming time (see “Initial Max” column).
6. Time between erase suspend resume and next erase suspend request.

3.15.3 Start-up/Switch-off timings

Table 35. Start-up time/Switch-off time

Symbol		C	Parameter	Conditions[1]	Value			Unit
					Min	Typ	Max	
$T_{FLARSTEXIT}$	CC	T	Delay for Flash module to exit reset mode	Code flash memory	—	—	125	µs
		T		Data flash memory	—	—	125	
$T_{FLALPEXIT}$	CC	D	Delay for Flash module to exit low-power mode	Code flash memory	—	—	0.5	
$T_{FLAPDEXIT}$	CC	T	Delay for Flash module to exit power-down mode	Code flash memory	—	—	30	
		T		Data flash memory	—	—	30	
$T_{FLALPENTRY}$	CC	D	Delay for Flash module to enter low-power mode	Code flash memory	—	—	0.5	

1. V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = –40 to 125 °C, unless otherwise specified.

3.16 AC specifications

3.16.1 Pad AC specifications

Table 36. Output pin transition times

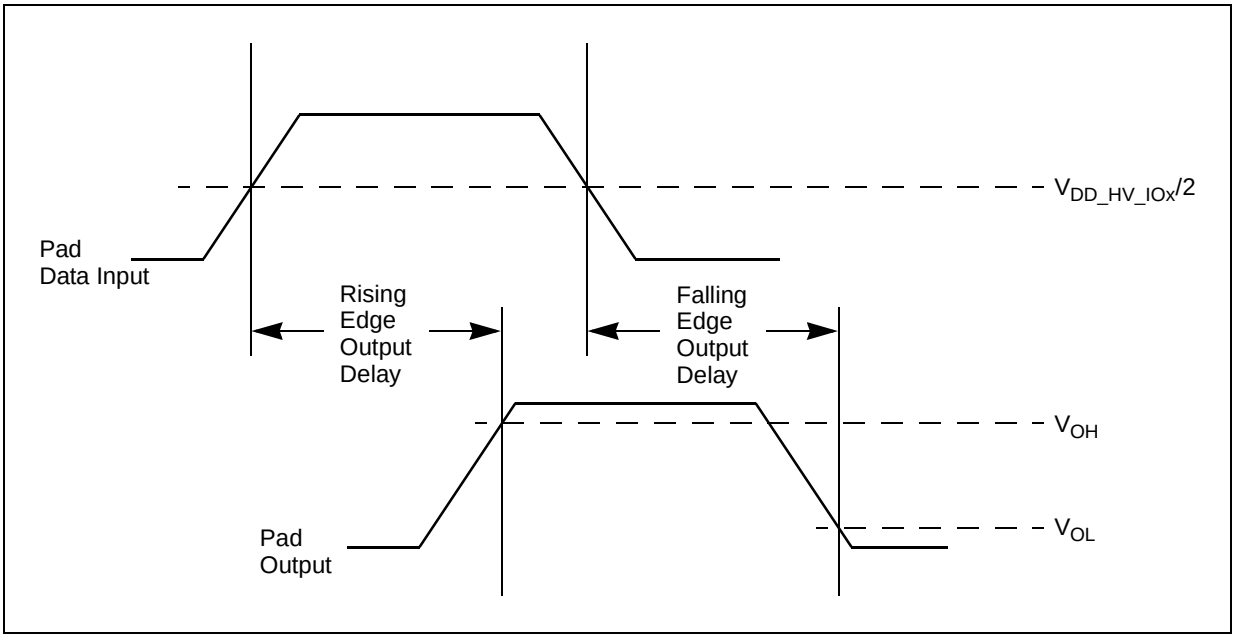
Symbol		C	Parameter	Conditions[1]		Value			Unit
						Min	Typ	Max	
t_{tr}	CC	D	Output transition time output pin[2] SLOW configuration	C_L = 25 pF	V_{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	50	ns
		T		C_L = 50 pF		—	—	100	
		D		C_L = 100 pF		—	—	125	
		D		C_L = 25 pF	V_{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	40	
		T		C_L = 50 pF		—	—	50	
		D		C_L = 100 pF		—	—	75	
t_{tr}	CC	D	Output transition time output pin[2] MEDIUM configuration	C_L = 25 pF	V_{DD} = 5.0 V ± 10%, PAD3V5V = 0 SIUL.PCRx.SRC = 1	—	—	10	ns
		T		C_L = 50 pF		—	—	20	
		D		C_L = 100 pF		—	—	40	
		D		C_L = 25 pF	V_{DD} = 3.3 V ± 10%, PAD3V5V = 1 SIUL.PCRx.SRC = 1	—	—	12	
		T		C_L = 50 pF		—	—	25	
		D		C_L = 100 pF		—	—	40	

Table 36. Output pin transition times (continued)

Symbol		C	Parameter	Conditions[1]		Value			Unit
						Min	Typ	Max	
t_{tr}	CC	D	Output transition time output pin[2] FAST configuration	C_L = 25 pF	V_{DD} = 5.0 V ± 10%, PAD3V5V = 0 SIUL.PCRx.SRC = 1	—	—	4	ns
				C_L = 50 pF		—	—	6	
				C_L = 100 pF		—	—	12	
				C_L = 25 pF	V_{DD} = 3.3 V ± 10%, PAD3V5V = 1 SIUL.PCRx.SRC = 1	—	—	4	
				C_L = 50 pF		—	—	7	
				C_L = 100 pF		—	—	12	
t_{SYM}[3]	CC	T	Symmetric transition time, same drive strength between N and P transistor	V_{DD} = 5.0 V ± 10%, PAD3V5V = 0		—	—	4	ns
				V_{DD} = 3.3 V ± 10%, PAD3V5V = 1		—	—	5	

1. V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = –40 °C to $T_{A\ MAX}$, unless otherwise specified.
2. C_L includes device and package capacitances (C_{PKG} < 5 pF).
3. Transition timing of both positive and negative slopes will differ maximum 50%.

Figure 19. Pad output delay

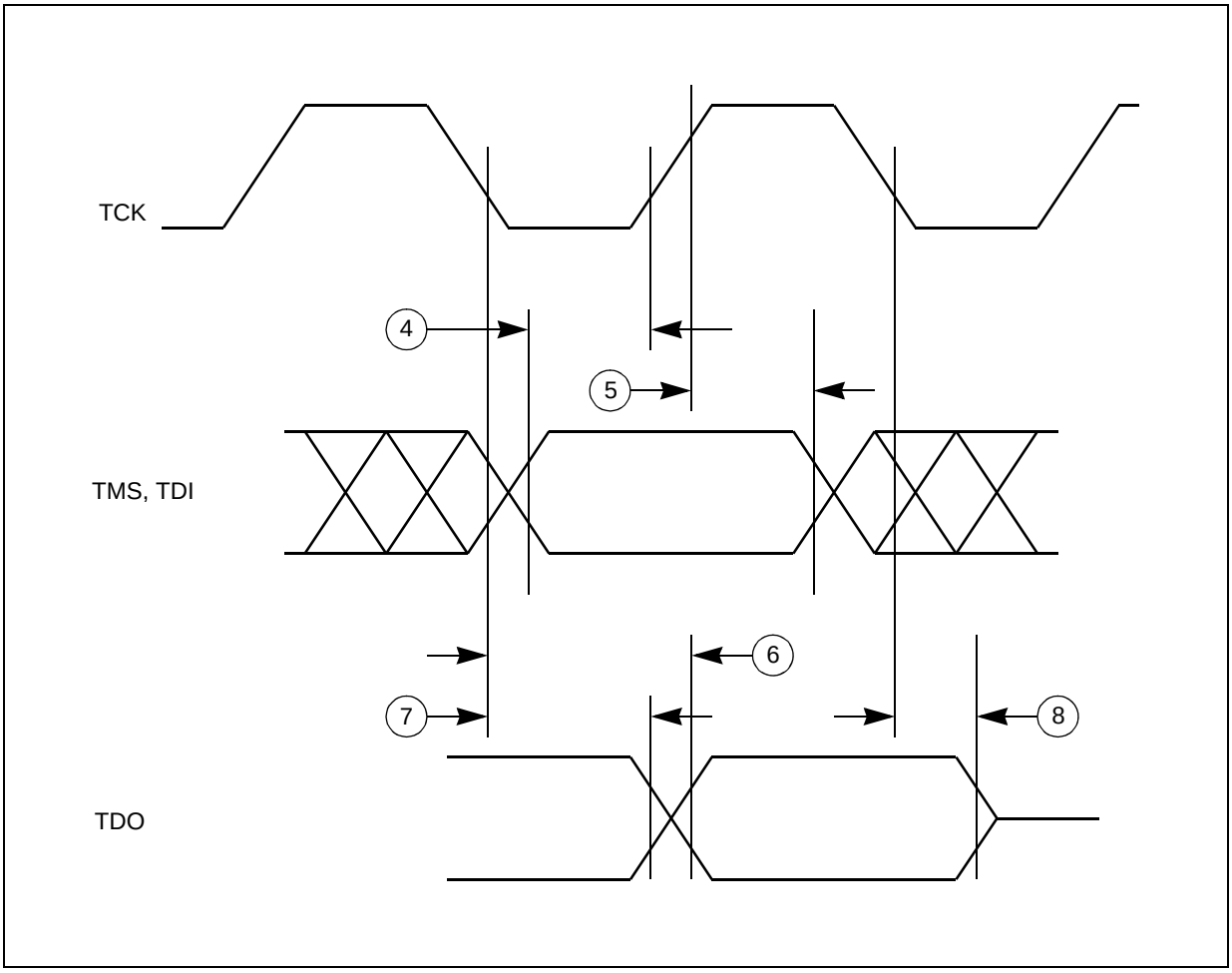


3.17 AC timing characteristics

3.17.1 $\overline{\text{RESET}}$ pin characteristics

The SPC560P34/SPC560P40 implements a dedicated bidirectional $\overline{\text{RESET}}$ pin.

Figure 23. JTAG test access port timing



4 Package characteristics

4.1 ECOPACK®

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

4.2.2 LQFP64 mechanical outline drawing

Figure 39. LQFP64 package mechanical drawing

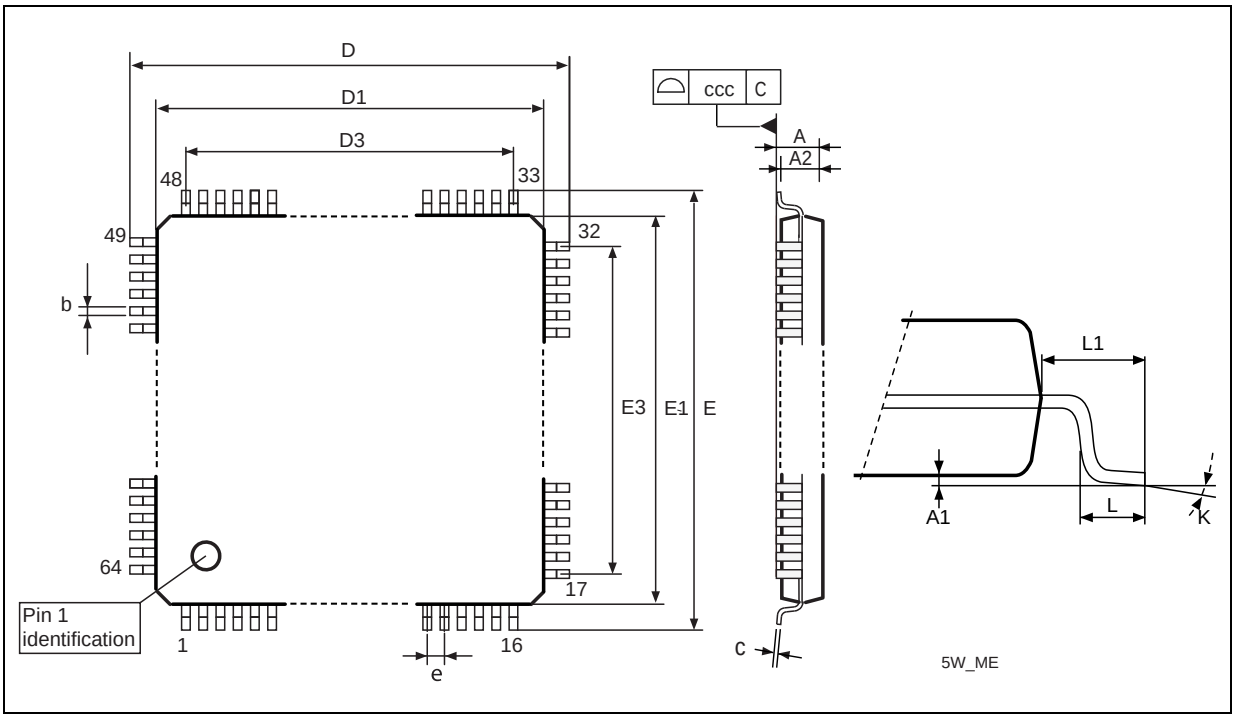


Table 43. LQFP64 package mechanical data

Symbol	Dimensions					
	mm			inches[1]		
	Min	Typ	Max	Min	Typ	Max
A	—	—	1.6	—	—	0.063
A1	0.05	—	0.15	0.002	—	0.0059
A2	1.35	1.4	1.45	0.0531	0.0551	0.0571
b	0.17	0.22	0.27	0.0067	0.0087	0.0106
c	0.09	—	0.2	0.0035	—	0.0079
D	11.8	12	12.2	0.4646	0.4724	0.4803
D1	9.8	10	10.2	0.3858	0.3937	0.4016
D3	—	7.5	—	—	0.2953	—
E	11.8	12	12.2	0.4646	0.4724	0.4803
E1	9.8	10	10.2	0.3858	0.3937	0.4016
E3	—	7.5	—	—	0.2953	—
e	—	0.5	—	—	0.0197	—
L	0.45	0.6	0.75	0.0177	0.0236	0.0295
L1	—	1	—	—	0.0394	—

Table 45. Document revision history (continued)

Date	Revision	Changes
21-May-2010	2 (continued)	– Updated the “DC electrical characteristics (3.3 V, NVUSRO[PAD3V5V] = 0)“ section: – Deleted all rows concerning $\overline{\text{RESET}}$ – Deleted “I_{VPP}“ row – Added the max value for C_{IN} Added the “I/O pad current specification“ section Updated the Order codes table. Added “Appendix A”
23-Dec-2010	3	“Introduction” section: – Changed title (was “Overview“) – Updated contents “SPC560P34/SPC560P40 device comparison” table: – Added sentence above table – Removed “FlexRay” row – “FlexCAN” row: removed link to footnote 2 for SPC560P34 – Updated “Safety port” row for SPC560P34 – Updated “DSPI” row for SPC560P34 “SPC560P34/SPC560P40 block diagram”: added the following blocks: MC_CGM, MC_ME, MC_PCU, MC_RGM, CRC, and SSCM Added “SPC560P34/SPC560P40 series block summary” table “Pin muxing” section: removed information on “Symmetric pads” “Electrical characteristics” section: – Updated “Caution” note – Demoted “NVUSRO register” section to subsection of “DC electrical characteristics” section – “NVUSRO register” section: deleted “NVUSRO[WATCHDOG_EN] field description“ section Updated “EMI testing specifications” table “Low voltage monitor electrical characteristics” table: updated $V_{MLVDDOK\_H}$ max value “DC electrical characteristics (5.0 V, NVUSRO[PAD3V5V] = 0)” table: removed $_{VOL\_SYM}$, and V_{OH_SYM} rows “Supply current (5.0 V, NVUSRO[PAD3V5V] = 0)” table: – $I_{DD\_LV\_CORE}$, RUN—Maximum mode, 40/64 MHz: updated typ/max values – $I_{DD\_LV\_CORE}$, RUN—Airbag mode, 40/64 MHz: updated typ/max values – $I_{DD\_LV\_CORE}$, RUN—Maximum mode, “P” parameter classification: removed – I_{DD_FLASH}: removed rows – I_{DD_ADC}, Maximum mode: updated typ/max values – I_{DD_OSC}: updated max value Updated “DC electrical characteristics (3.3 V, NVUSRO[PAD3V5V] = 1)” table “Supply current (3.3 V, NVUSRO[PAD3V5V] = 1)” table: – $I_{DD\_LV\_CORE}$, RUN—Maximum mode, 40/64 MHz: updated typ/max values – $I_{DD\_LV\_CORE}$, RUN—Airbag mode, 40/64 MHz: updated typ/max values – I_{DD_FLASH}: removed rows – I_{DD_ADC}, Maximum mode: updated typ/max values – I_{DD_OSC}: updated max value Added “I/O consumption” table Removed “I/O weight” table

Table 45. Document revision history (continued)

Date	Revision	Changes
23-Dec-2010	3 (continued)	Updated “Main oscillator electrical characteristics (5.0 V, NVUSRO[PAD3V5V] = 0)” table Updated “Main oscillator electrical characteristics (3.3 V, NVUSRO[PAD3V5V] = 1)” table “Input clock characteristics” table: updated f_{CLK} max value “PLLMRFM electrical specifications (V_{DDPLL} = 1.08 V to 1.32 V, V_{SS} = V_{SSPLL} = 0 V, T_A = T_L to T_H)” table: – Updated supply voltage range for V_{DDPLL} in the table title – Updated f_{SCM} max value – Updated C_{JITTER} row – Updated f_{MOD} max value Updated “16 MHz RC oscillator electrical characteristics” table Updated “ADC conversion characteristics” table “Program and erase specifications” table: – $T_{wprogram}$: updated initial max and max values – T_{BKPRG}, 64 KB: updated initial max and max values – added information about “erase time” for Data Flash “Flash module life” table: – P/E, 32 KB: added typ value – P/E, 128 KB: added typ value Replaced “Pad AC specifications (5.0 V, NVUSRO[PAD3V5V] = 0)” and “Pad AC specifications (3.3 V, INVUSRO[PAD3V5V] = 1)” tables with “Output pin transition times” table “JTAG pin AC electrical characteristics” table: – t_{TDOV}: updated max value – t_{TDOHZ}: added min value and removed max value “Nexus debug port timing” table: removed the rows “t_{MCYC}”, “t_{MDOV}”, “t_{MSEOV}”, and “t_{EVTOV}” Updated “External interrupt timing (IRQ pin)” table Updated “FlexCAN timing” table Updated “DSPI timing” table Updated “Ordering information” section